NSN 5961-01-074-8422



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-074-8422 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches Overall Diameter: 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To.66 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -20.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage/static/base open and -7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between -2.00 amperes source cutoff current and -4.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector preset **Special Features:** Item must comply with requirements of defense electronics supply center production standard no. L02688; for navy nuclear propulsion plant products only; junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:**

No Fiig:

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Demilitarization: